

PATENT NUMBER

U.S. UTILITY Patent Application

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SCANNED TO Q.A.	
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APPLICATION NO. CONT/PRIOR CLASS SUBCLASS ART UNIT **EXAMINER** 09/516615 2 91 257 2811

Douglas Coolbaugh Gregory Freeman Seshadri Subbanna

Method of fabricating a polysilicon capačitor utilizing fet and bipolar base polysilicon layers

ISSUING CLASSIFICATION							
ORIGIN	AL pr	CROSS REFERENCE(S)					
CLASS	SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)				
257 INTERNATIONAL	29 6 L CLASSIFICATION	257	532				
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11011 C	29/00		☐ Continued on Issue Slip Inside File Jacket				

TERMINAL	DRAWINGS			CLAIMS ALLOWED		
☐ DISCLAIMER	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.	
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☐ The term of this patent		•		NOTICE OF ALL	OWANCE MAILED	
subsequent to (date) has been disclaimed.	(Assistant E	Examiner)	(Date)	.,,	<i>((((((((((</i>	
The term of this patent shall not extend beyond the expiration date	Regly			11-05-02		
of U.S Patent. No.				ISSUE FEE		
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WARNING:		,				
The information disclosed herein may be res Possession outside the U.S. Patent & Traden					5, Sections 122, 181 and 368.	
Form PTO-436A Rev. 6/99)			FILED WITH:		FICHE CD-ROM	